Microwave Irradiation Effect on Structural, Optical, and Thermal Properties of Cadmium Oxide Nanostructure

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Cadmium oxide nanostructures were prepared by microwave assisted wet chemical technique at different time intervals. Results on structural, optical, and thermal properties of the CdO nanostructures as a function of the microwave irradiation were reported. The X-ray diffraction data indicates that the sample showed perfection in the microstructural improvement as a function of microwave irradiation. Surface morphological changes with different time of microwave irradiation were recorded by transmission electron microscope and the particle size were found in the ranges from 5 to 30 nm. Chemical composition and thermal stability of the samples were analyzed by energy dispersive X-ray spectrum and thermogravimetric analysis, respectively. The band gaps were shifted towards the blue region due to the Moss–Burstein effect and it exhibited direct band transitions, which corresponds to optical band gaps of 3.92–4.20 eV and contrast behavior of optical properties of CdO nanostructure in UV and IR regions were registered. Room temperature photoluminescence spectra revealed that the intensity of luminescent emission tends to decrease with the increase in exposure of microwave irradiation.

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1. Introduction

In the past decade, nanocrystallites have attracted more attention in both fundamental research and practical application for their quantum confinement phenomenon. It is generally known that nanostructured materials display unusual physical properties that differ from those of bulk materials and are promising for the fabrication of novel devices. In recent years, a wide range of nanosized powders have been synthesized to engineer desired properties such as chemical, electrical, mechanical, and optical properties [1].

Nowadays semiconductor nanostructures attract a lot of interest due to their wide applications in the electrical and optoelectronic devices. From the optical point of view the interest is connected with a possibility of tuning the light emission from semiconductor nanocrystals (NCs) by varying their size, owing to the effect of quantum confinement [2]. The use of transparent conducting oxides (TCO) in optoelectronic and photovoltaic devices has stimulated research on this field in recent years.

In particular, cadmium oxide is a promising material for solar cell application [3–5] and photodiodes [6]. A variety of techniques have been reported to make CdO nanostructures like sol–gel [7], DC magnetron sputtering [8], radio-frequency sputtering [9], spray pyrolysis [10], pulsed laser deposition [11], chemical vapor deposition [12], chemical bath deposition [13], hydrothermal [14] and solvothermal [15] but few works on the preparation and characterization of CdO nanoparticles by microwave assisted technique. In contrast, our focus arises toward synthesis of cadmium oxide using microwave assisted wet chemical route, because microwaves are directly coupled with the material result in rapid and uniform heating. In the present work, we have registered the changes of structural and optical properties (reflectance, band gap, absorption and extinction coefficient, refractive index, dielectric constant and optical conductivity) of cadmium oxide nanostructure with the effect of microwave irradiation at three different time intervals. Several researchers have reported that [8, 16–18] the optical properties of CdO nanoparticles have been achieved by the process of annealing with huge time (i.e., require high energy consumption) but in our present method we achieved good quality crystalline CdO nanostructures with fine optical property within 5–15 min with low energy consumption. Up to our knowledge, there is not any reported data about the vast optical constants of cadmium oxide samples with effect of microwave irradiation based on the diffused reflectance calculations.

2. Experimental

2.1. Synthesis

In order to prepare CdO, precursor solution cadmium acetate dihydrate (Cd(COOCH\textsubscript{3})\textsubscript{2}·2H\textsubscript{2}O) with a concentration of 0.1 M was prepared separately. Subsequently, ammonia (NH\textsubscript{4}OH) solution was added to the above solution. The resulting mixture was stirred at room tem-
peratures until the pH of the solution is 8. The resulting precipitate was washed with double distilled water. The obtained precipitate was placed in a microwave oven (2.45 GHz, 800 W) and irradiated for 5 min (sample A), 10 min (sample B) and 15 min (sample C), and finally the precipitate was filtered and dried at 120 °C.

2.2. Characterization

The crystalline structure of the samples was analyzed by X-ray diffraction (XRD) using a Bruker AXS D8 Advance instrument and using the Cu Kα wavelength of 1.5406 Å. The average crystallite size of the CdO phases were evaluated using the Scherrer formula $d = \frac{k\lambda}{\beta\cos\theta}$, where $d$ is the mean crystallite size, $k$ is a grain shape dependent constant (0.9), $\lambda$ is the wavelength of the incident beam, $\beta$ is a Bragg reflection angle, and $\theta$ is the full width half maximum. Transmission electron microscopy (TEM) analysis was performed on a Philips instrument Model CM12 operating at 120 kV and directly interfaced with a computer for real-time image processing. Energy dispersive X-ray spectroscopy (EDX) analysis was observed by JEOL JSM600LV microscope at an accelerating voltage of 10 kV. The diffused reflectance spectroscopy (DRS) reflectance spectra were studied using UV-DRS absorption spectroscopy - Specord S600-212C205 UV Spectrophotometer. Photoluminescence spectrum was carried out using Spectrofluorometer - Fluorolog - FL3-11. Thermal stability of the sample was examined by using a Perkin Elmer Diamond TGA instrument under N2 atmosphere.

3. Results and discussion

3.1. Structural characterizations

Figure 1a-c shows the X-ray diffraction pattern of microwave irradiated CdO nanostructure with different time intervals i.e., 5 (sample A), 10 (sample B), and 15 (sample C) min, respectively. From the figure, formation of crystalline CdO phase has been clearly registered. In fact, the sharp peaks indicate that the irradiated samples A, B and C possess high crystallinity. Further, no traces of impurity phases such as CdO2, Cd(OH)2, and CdCO3 are detected in the XRD pattern, indicating the formation of CdO crystalline phase. The as-prepared samples exhibited the following Miller indices [111], [200], [220], [311], and [222] which is matched well with ICDD card #65-2908 and face-centered cubic structure of CdO [17]. The average crystalline size of the cadmium oxide crystals were calculated from the Scherrer equation and it was found to be 25 to 51 nm i.e., the average crystalline size increases when exposing the microwave irradiation time increases.

In general, microwave synthesis is quite fast, simple, and very energy efficient. The exact nature of microwave interaction with reactants during the synthesis of materials is somewhat unclear and speculative. However, transfer of energy from microwaves to the material is believed to occur either through resonance or relaxation, which results in rapid heating and also greatly accelerated the nucleation of the crystalline CdO form. The amount of defects can be estimated by calculating the dislocation line density ($\delta$) which is related to particle size ($D$) as $\delta = n/D^2$. (1) From this relation [19-21], it is obvious that as the particle size increases, the dislocation density decreases. In our case, microwave irradiation increases, the dislocation line density decreases depicting the reduction of defects density, which implies improved crystallinity.

3.2. Surface morphological analysis

The surface morphology of CdO nanostructures of samples A, B, and C were recorded by TEM microscope as shown in Fig. 2a,c,e. The microwave irradiation with the function of time on cadmium hydroxide solution accelerates the surface structure. Agglomerated irregular shaped CdO nanostructures were obtained when exposure of microwave irradiation time was 5 min (Fig. 2a) and an irradiation time was increased 10 min then irregular shapes were transformed into spherical shape (Fig. 2c). Finally rod like shape structures are obtained when microwave irradiation increased for 15 min in the range of 50–80 nm. The thickness and length of nano rod has 25–40 nm and of few µm (Fig. 2e). From the observed behavior one can suggest increase of the exposing time of microwave irradiation on cadmium hydroxide solution tunes the surface morphology of CdO. The DEX spectrum of CdO nanostructures of samples A, B, and C were shown in Fig. 2b,d,f. The compositional analysis of the samples (A, B, and C) was confirmed by EDX analysis and the results are shown in Fig. 2b,d,f. The Cd and O peaks are present in the DEX spectra and this confirms the formation of CdO.

3.3. Optical studies (DRS)

The optical constants of the microwave irradiated cadmium oxide nanostructure samples A, B, and C were determined by UV-DRS spectra (before that, samples were
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Fig. 2. TEM images (a, c, e) and corresponding EDX pattern (b, d, f) of the samples A, B, and C.

Fig. 3. Diffused reflectance spectrum as a function of wavelength for CdO samples A, B, and C.

prepared by thick film on glass substrate). From Fig. 3 it is clear that the reflectance of the samples increases with increasing wavelength. Minimum reflectance is observed in UV region then it starts to increase in visible region and reaches maximum in IR region. Exposure of microwave irradiation time increases causes reflectance increases in UV region but it exhibits opposite behavior in IR region i.e., as the microwave irradiation time increases the reflectance value decreases.

To obtain the optical band gap of the microwave irradiated CdO samples at room temperature, the Kubelka-Munk theory is generally used and it is expressed by the following relation [22]:

\[ F(R) = \frac{(1 - R)^2}{2R}, \]  

where \( F(R) \) is the Kubelka-Munk function and \( R \) is the reflectance. The electronic transition between the valence and conduction bands starts at the absorption edge corresponding to the minimum energy difference between the lowest energy of the conduction band and the highest energy of the valence band in crystalline materials. The optical band gap was determined from the relation, \( (\alpha h \nu) = (h \nu - E_g)^n \), where \( \alpha \) is the linear absorption coefficient of the material, \( E_g \) is the optical band gap and \( n \) is a constant which determines the type of optical transitions: for \( n = 1/2 \), \( 3/2 \), \( 2 \), and \( 3 \) depending on the nature of the electronic transition responsible for the absorption:

- \( n = 1/2 \) for allowed direct transition,
- \( n = 3/2 \) for forbidden direct transition and
- \( n = 3 \) for forbidden indirect transition [23-25].

\( F(R) \) is directly proportional to the absorbance therefore; \( F(R) \) values were converted to the linear absorption coefficient by means of the \( \alpha = \text{absorbance}/t = F(R)/t \) relation, where \( t \) is the thickness of the film. The curve of [\( F(R)h\nu/t \)]^{1/2} vs. \( h\nu \) for the CdO samples A, B, and C was plotted [26] as shown in Fig. 4. The direct band gap values were determined by extrapolating the linear portions of these graphs to the energy axis at \( F(R) = 0 \) and was found to be 3.92, 4.09, 4.20 eV for samples A, B, and C respectively, i.e., the microwave irradiation time increase causes the band gap value increase. The obtained values are higher than the bulk CdO [27-30]. The higher direct band gap value with effect of microwave irradiation in the present work is believed to be partly due to the Moss-Burstein (M-B) effect. The blue-shift of the absorption edge has been generally interpreted by the M-B effect [22, 31]. The higher value of optical band gap arises due to improvement in the crystallinity of CdO during microwave irradiation and this confirms the quantum confinement. Several researchers [7, 16, 17, 30] obtained band gap values of 2.29 eV at 450°C for 120 min, 2.26 eV at 400°C, 2.7 eV at 623 K for 2 h, 2.79-2.50 eV at 200°C-450°C for CdO samples by various methods. But the present work yields the higher band gap value of CdO nanostructure than bulk CdO without post synthesis of annealing and low energy consumption suggests the applicability of the material under this method in optoelectronic field.

The refractive index \( n \) and extinction coefficient \( k \) of the CdO samples (A, B, C) can be calculated by using following relation [32, 33]:

\[ n = \left( \frac{1 + R}{1 - R} \right) + \left[ \frac{4R}{(1 - R)^2} - k^2 \right]^{1/2}, \]  

\[ k = \frac{\alpha \lambda}{4\pi}. \]

(Fig. 5 shows the dependence of the refractive index of the microwave irradiated CdO samples on wavelength. The refractive index of all samples lies between 2 and 5.99. The dispersion curve of refractive index is lower in the UV region and rises rapidly towards IR re-
maximum for minimum microwave irradiation exposure time and decreases gradually as the exposure time increases and sample A exhibits more transparency in IR region than sample B and C. Figure 6b shows the variation of extinction coefficient \(k\) with wavelength \(\lambda\) for microwave irradiated CdO samples. It is clear from Fig. 6b that the values of \(k\) changed in the range 0.00010–0.00025 and that the values of \(k\) increase with increase in wavelength. The low value of extinction coefficient represents samples possessing high transmittance.

The frequency dependence of the complex electronic dielectric constant is defined as \(\varepsilon(\omega) = \varepsilon_1(\omega) + i\varepsilon_2(\omega)\). These two contributions represent the in-phase \(\varepsilon_1\) and out-of-phase \(\varepsilon_2\) components of the frequency response of the medium. The in-phase component results in dispersion, physically this means refraction of the electromagnetic radiation as it passes through the medium and the out-of-phase component gives rise to absorption. Real and imaginary parts of the dielectric constant are related to the \(n\) and \(k\) values. The \(\varepsilon_1\) and \(\varepsilon_2\) values were calculated using the formulae [34, 35]:

\[
\varepsilon_1 = n^2 - k^2, \tag{5}
\]

\[
\varepsilon_2 = 2nk. \tag{6}
\]
The variation of $\varepsilon_1$ and $\varepsilon_2$ values of the microwave irradiated CdO samples A, B, and C with wavelength is shown in Fig. 7a,b. It can be seen in Fig. 7a that the real part dielectric constant is less in UV region, then it starts increasing with increase in wavelength. The variations of dielectric constant with wavelength may be due to the presence of all types of polarizations namely, space charge, orientational, electronic and ionic polarization, and its losses. The characteristic of low dielectric constant suggests that the sample possesses optical quality with lesser defects and this parameter is highly important for making optoelectronic materials. It is seen from Fig. 7a that the spectral variation of $\varepsilon_1$ is quite similar to those of the refractive index. This is an expected situation, since extinction coefficient is too small ($\approx 0.0020$ in maximum) to make any significant contribution to the variation of real part of dielectric coefficient. An imaginary part of the dielectric constant is increased with wavelength increases as shown in Fig. 7b.

The real ($\sigma_1$) and imaginary ($\sigma_2$) parts of the optical conductivity are expressed by [36]:

$$\sigma_1 = \omega \varepsilon_2 \varepsilon_0,$$

$$\sigma_2 = \omega \varepsilon_1 \varepsilon_0,$$

where $\omega$ is the angular frequency and $\varepsilon_0$ is the free space dielectric constant. The dependence of the real and imaginary parts of the optical conductivity on the wavelength is shown in Fig. 8a,b. Figure 8a shows that the maximum real part of the optical conductivity is observed in UV region then decreases towards IR region. Figure 8b shows that the minimum and maximum imaginary part of the optical conductivity is observed in UV and IR regions, respectively, then it starts to decrease in the higher wavelength. The variations of optical conductivity due to reduction of polarization and crystal defects are created by thermal activation with exposure of microwave irradiation at different time intervals. The variation of the optical conductivity may be the availability of impurities and vacancies in the crystal lattice due to exposure of microwave irradiation at different time intervals.

As can be seen from Figs. 3-8 it is demonstrated that the optical properties of sample A varying from sample B and C. One can also evident from Figs. 3-8 that the optical properties of CdO nanostructures in UV region are opposite to that of IR region and the significant occurrence may be exposure of microwave irradiation at different time intervals. According to Eq. (1), crystal defect decreases due to increase of particle size when the microwave irradiation time increases. When the material was irradiated by microwave the vacancies,
foreign impurities incorporated into the lattice and the molecular structure will change and this change is combined with the polarization properties of the material which will have an influence on the thermal coefficient of dielectric constant of the material. Usually, dielectric materials have permanent dipoles. As microwave irradiation increases, the molecules in the dielectric have more thermal energy and therefore, the amplitude of random motion is greater. This means that the molecules are less closely aligned with each other (even in the presence of an electric field). Hence, the optical property gets altered.

3.4. Photoluminescence studies

The photoluminescence (PL) spectra of microwave irradiated cadmium oxide samples A, B, and C are shown in Fig. 9. From the figure, it is clearly evident that all the samples exhibited the strong emission peak at 529 nm (2.3 eV). Zaien and co-workers [37] reported that the emission peak of bulk CdO is 491 nm (2.5 eV). This red-shift from 2.3 to 2.5 eV was caused by the formation of donor levels (the Fermi levels) near the conduction band of the CdO nanostructures [37]. Moreover, it can be seen from Fig. 9 samples B and C show the similar spectra but it is different from sample A that the intensity of luminescent emission decreases with increase in the exposure of microwave irradiation time, and it is attributed to the decrease in oxygen vacancies as a function of microwave irradiation.

![Fig. 9. Photoluminescence spectrum of CdO nanostructure samples A, B, and C.](image)

3.5. Thermogravimetric analysis

Thermogravimetric analysis was recorded for as-prepared cadmium oxide nanostructure heated to 700 °C with a ramp rate of 20 °C/min under N₂ atmosphere and is shown in Fig. 10. The first weight loss of about 3% occurring from room temperature to 220 °C could be attributed to the release of surface adsorbed water [38]. The second major weight loss happening at 220-350 °C and weight loss of 12.4% was measured, corresponding to release of water molecule from interior of cadmium oxide nanostructure [39]. The third weight loss 7.7% at 600°C may be related to the decomposition of organic groups in the precursor [38]. There is no weight loss observed after 550°C, implying the as-synthesized CdO is stable up to this temperature.

![Fig. 10. TGA spectra of sample A in N₂ atmosphere.](image)

4. Conclusion

This work describes a novel approach to synthesis of cadmium oxide nanostructure by microwave assisted wet chemical technique at different time intervals. XRD data indicates that samples show microstructural perfection improvement as a function of microwave irradiation and confirms face-centered cubic structure of the samples. From the behavior observed from TEM micrograph, it is possible to tune the morphology of the CdO nanostructure when microwave irradiation time increases. The peaks of Cd and O show that the formation of CdO was confirmed by EDX. Contradicting optical properties of CdO in UV and IR region were recorded by DRS spectrum. The photoluminescence study showed decrease in the luminescent emission with the increase in exposure of microwave irradiation. By tuning the microwave irradiation, one can get required higher optical band gap of CdO for required optoelectronic applications.

References

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